

KLT-USB1A-FF-IMX335 V2.0**Sony IMX335 USB Interface Foco Fixo 5MP M12 Módulo de Câmera**

Módulo de câmara No.	KLT-USB1A-FF-IMX335 V2.0	
Sensor de imagem	IMX335	Output Format: MJPG, YVY2
EFL	3.71 mm	30 FPS 2592 x 1944 (Full Frame)
F.NO	2.1	30 FPS 1920 x 1080 (Full HD)
Pixel	2592 x 1944	30 FPS 1280 x 720 (HD 720P)
Ângulo de visão	129°(D) 100.6°(H) 51.9°(V)	Supporting OS
Tipo de lente	1/2.8 polegada	Windows 7, 8.1, 10, Vista
Dimensões da lente	16.30 x 16.30 x 22.10 mm	Windows XP SP2 under UVC
Tamanho do Módulo	38.00 x 38.00 mm	Linux Kernel V2.6.2.1 or later
Tipo de Módulo	Foco Fixo	MAC OS 10.4 or later
Interface	USB	Compliant with UVC Version 1.0

Número da peça do cabo USB de acoplamento. KLT-USB1A-Cable

Cabo de extensão USB. Vendido separadamente

[Product Information]

Ver.1.0

IMX335LLN

Diagonal 6.52 mm (Type 1 / 2.8) CMOS Solid-state Image Sensor with Square Pixel for Monochrome Cameras

Description

The IMX335LLN is a diagonal 6.52 mm (Type 1 / 2.8) CMOS active pixel type solid-state image sensor with a square pixel array and 5.14 M effective pixels. This chip operates with analog 2.9 V, digital 1.2 V, and interface 1.8 V triple power supply, and has low power consumption. High sensitivity, low dark current and no smear are achieved. This chip features an electronic shutter with variable charge-integration time.
(Applications: Surveillance cameras, FA cameras, Industrial cameras)

Features

- ◆ CMOS active pixel type dots
- ◆ Built-in timing adjustment circuit, H/V driver and serial communication circuit
- ◆ Input frequency: 6 to 27 MHz / 37.125 MHz / 74.25 MHz
- ◆ Number of recommended recording pixels: 2592 (H) × 1944 (V) approx. 5.04 M pixels
- ◆ Readout mode
 - All-pixel scan mode
 - Window cropping mode
 - Vertical / Horizontal direction-normal / inverted readout mode
- ◆ Readout rate
 - Maximum frame rate in All-pixel scan mode 2592(H) × 1944(V) A/D 10-bit : 60 frame/s
- ◆ High dynamic range (HDR) function
 - Multiple exposure HDR
 - Digital overlap HDR
- ◆ Variable-speed shutter function (resolution 1H units)
- ◆ 10-bit / 12-bit A/D converter
- ◆ CDS / PGA function
 - 0 dB to 30 dB : Analog Gain 30 dB (step pitch 0.3 dB)
 - 30.3 dB to 72 dB : Analog Gain 30 dB + Digital Gain 0.3 to 42 dB (step pitch 0.3 dB)
- ◆ Supports I/O
 - CSI-2 serial data output (2 Lane / 4 Lane, RAW10 / RAW12 output)
- ◆ Recommended exit pupil distance: -100 mm to $-\infty$

STARVIS

* STARVIS is a trademark of Sony Corporation. The STARVIS is back-illuminated pixel technology used in CMOS image sensors for surveillance camera applications. It features a sensitivity of 2000 mV or more per $1 \mu\text{m}^2$ (color product, when imaging with a 706 cd/m^2 light source, F5.6 in 1 s accumulation equivalent), and realizes high picture quality in the visible-light and near infrared light regions.

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Sony logo is a registered trademark of Sony Corporation.

Device Structure

- ◆ CMOS image sensor
- ◆ Image size
Type 1/2.8
- ◆ Total number of pixels
2704 (H) × 2104 (V) approx. 5.69 M pixels
- ◆ Number of effective pixels
2616 (H) × 1964 (V) approx. 5.14 M pixels
- ◆ Number of active pixels
2616 (H) × 1960 (V) approx. 5.13 M pixels
- ◆ Number of recommended recording pixels
2592 (H) × 1944 (V) approx. 5.04 M pixels
- ◆ Unit cell size
2.0 μm (H) × 2.0 μm (V)
- ◆ Optical black
Horizontal (H) direction: Front 0 pixel, rear 0 pixel
Vertical (V) direction: Front 13 pixels, rear 0 pixel
- ◆ Dummy
Horizontal (H) direction: Front 0 pixel, rear 0 pixel
Vertical (V) direction: Front 0 pixel, rear 0 pixel
- ◆ Package
88 pin BGA

Image Sensor Characteristics

(Tj = 60 °C)

Item		Value	Remarks
Sensitivity (F8)	Typ.	1961 Digit	1/30 s accumulation 12 bit converted value
Saturation signal	Min.	3895 Digit	12 bit converted value

Basic Drive Mode

Drive mode	Recommended number of recording pixels	Maximum frame rate [frame/s]	Output interface	ADC [bit]
All pixel	2592 (H) × 1944 (V) approx. 5.04 M pixels	60	CSI-2	10

[Product Information]

IMX335LQN

Ver.1.1

Diagonal 6.52 mm (Type 1/2.8) CMOS Solid-state Image Sensor with Square Pixel for Color Cameras

Description

The IMX335LQN is a diagonal 6.52 mm (Type 1/2.8) CMOS active pixel type solid-state image sensor with a square pixel array and 5.14 M effective pixels. This chip operates with analog 2.9 V, digital 1.2 V, and interface 1.8 V triple power supply, and has low power consumption. High sensitivity, low dark current and no smear are achieved through the adoption of R, G and B primary color mosaic filters. This chip features an electronic shutter with variable charge-integration time.

(Applications: Surveillance cameras, FA cameras, Industrial cameras)

Features

- ◆ CMOS active pixel type dots
- ◆ Built-in timing adjustment circuit, H/V driver and serial communication circuit
- ◆ Input frequency: 6 to 27 MHz / 37.125 MHz / 74.25 MHz
- ◆ Number of recommended recording pixels: 2592 (H) × 1944 (V) approx. 5.04 M pixels
- ◆ Readout mode
 - All-pixel scan mode
 - Horizontal/Vertical 2/2-line binning mode
 - Window cropping mode
 - Vertical / Horizontal direction-normal / inverted readout mode
- ◆ Readout rate
 - Maximum frame rate in All-pixel scan mode 2592 (H) × 1944 (V) A/D 10-bit : 60 frame/s
- ◆ High dynamic range (HDR) function
 - Multiple exposure HDR
 - Digital overlap HDR
- ◆ Variable-speed shutter function (resolution 1H units)
- ◆ 10-bit / 12-bit A/D converter
- ◆ CDS / PGA function
 - 0 dB to 30 dB : Analog Gain 30 dB (step pitch 0.3 dB)
 - 30.3 dB to 72 dB : Analog Gain 30 dB + Digital Gain 0.3 to 42 dB (step pitch 0.3 dB)
- ◆ Supports I/O
 - CSI-2 serial data output (2 Lane / 4 Lane, RAW10 / RAW12 output)
- ◆ Recommended exit pupil distance: -30 mm to $-\infty$

STARVIS

* STARVIS is a trademark of Sony Corporation. The STARVIS is back-illuminated pixel technology used in CMOS image sensors for surveillance camera applications. It features a sensitivity of 2000 mV or more per $1 \mu\text{m}^2$ (color product, when imaging with a 706 cd/m^2 light source, F5.6 in 1 s accumulation equivalent), and realizes high picture quality in the visible-light and near infrared light regions.

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Device Structure

◆ CMOS image sensor	Type 1/2.8
◆ Image size	2704 (H) × 2104 (V) approx. 5.69 M pixels
◆ Total number of pixels	2616 (H) × 1964 (V) approx. 5.14 M pixels
◆ Number of effective pixels	2616 (H) × 1960 (V) approx. 5.11 M pixels
◆ Number of active pixels	2592 (H) × 1944 (V) approx. 5.04 M pixels
◆ Number of recommended recording pixels	2.0 μm (H) × 2.0 μm (V)
◆ Unit cell size	Horizontal (H) direction: Front 0 pixel, rear 0 pixel
◆ Optical black	Vertical (V) direction: Front 13 pixels, rear 0 pixel
◆ Dummy	Horizontal (H) direction: Front 0 pixel, rear 0 pixel
	Vertical (V) direction: Front 0 pixel, rear 0 pixel
◆ Package	88 pin CSP BGA

Image Sensor Characteristics

(Tj = 60 °C)

Item		Value	Remarks
Sensitivity (F5.6)	Typ.	2200 Digit	1/30 s accumulation 12 bit converted value
Saturation signal	Min.	3895 Digit	12 bit converted value

Basic Drive Mode

Drive mode	Recommended number of recording pixels	Maximum frame rate [frame/s]	Output interface	ADC [bit]
All pixel	2592 (H) × 1944 (V) approx. 5.04 M pixels	60	CSI-2	10
Horizontal/ Vertical 2/2-line binning	1296 (H) × 972 (V) approx. 1.26 M pixels	60	CSI-2	10